## NSN 5961-00-752-5421

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View Online at https://aerobasegroup.com/nsn/5961-00-752-5421 **Inclosure Material:** Metal **Overall Length:** 0.500 inches **Overall Diameter:** 0.650 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, collector-to-base, emitter open and 45.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current and 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 pin **Specification Data:** 80131-release1719 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: